8-bit parallel-in/serial out shift register Rev. 5 — 9 August 2021

1. General description

The 74HC166; 74HCT166 is an 8-bit serial or parallel-in/serial-out shift register. The device features a serial data input (DS), eight parallel data inputs (D0 to D7) and a serial output (Q7). When the parallel enable input (PE) is LOW, the data from D0 to D7 is loaded into the shift register on the next LOW-to-HIGH transition of the clock input (CP). When PE is HIGH, data enters the register serially at DS with each LOW-to-HIGH transitions of CP. When the clock enable input (\overline{CE}) is LOW data is shifted on the LOW-to-HIGH transitions of CP. A HIGH on \overline{CE} disables the CP input. Inputs include clamp diodes which enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Synchronous parallel-to-serial applications
- Synchronous serial input for easy expansion
- Input levels:
 - For 74HC166: CMOS level
 - For 74HCT166: TTL level
- Complies with JEDEC standards:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

3. Ordering information

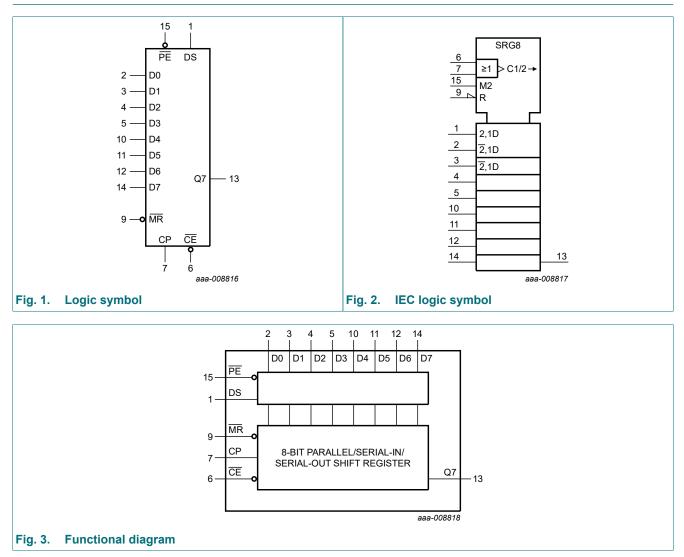
Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC166D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT166D				
74HC166PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1
74HCT166PW			body width 4.4 mm	

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4. Functional diagram

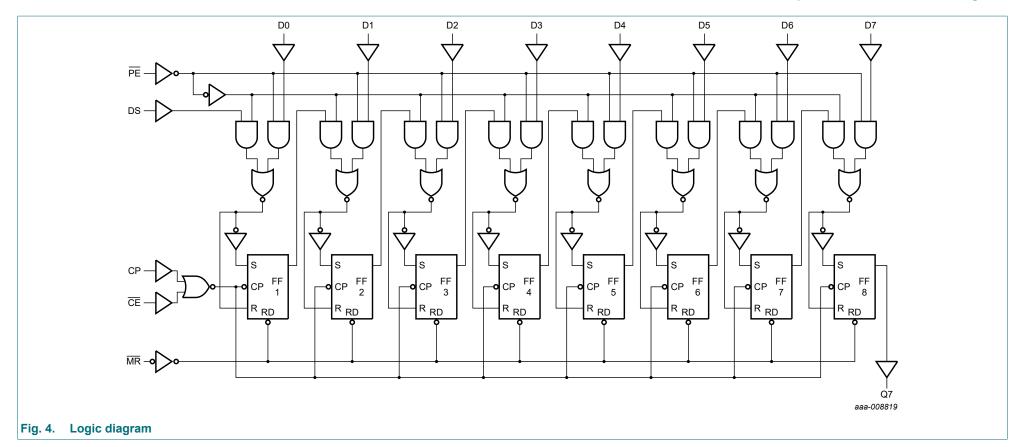


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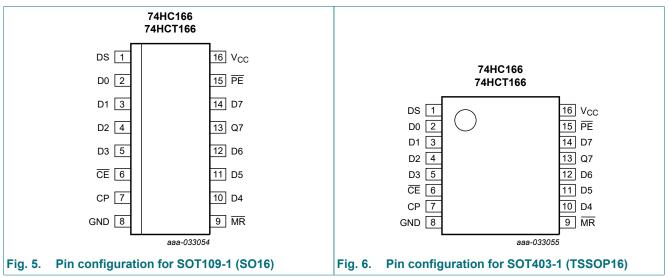
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74HC166; 74HCT166

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5. Pinning information



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5.2. Pin description

Table 2. Pin descrip	tion	
Symbol	Pin	Description
DS	1	serial data input
D0 to D7	2, 3, 4, 5, 10, 11, 12, 14	parallel data inputs
CE	6	clock enable input (active LOW)
СР	7	clock input (LOW-to-HIGH edge-triggered)
GND	8	ground (0 V)
MR	9	asynchronous master reset (active LOW)
Q7	13	serial output from the last stage
PE	15	parallel enable input (active LOW)
V _{CC}	16	positive supply voltage

5.1. Pinning

6. Functional description

Table 3. Function table

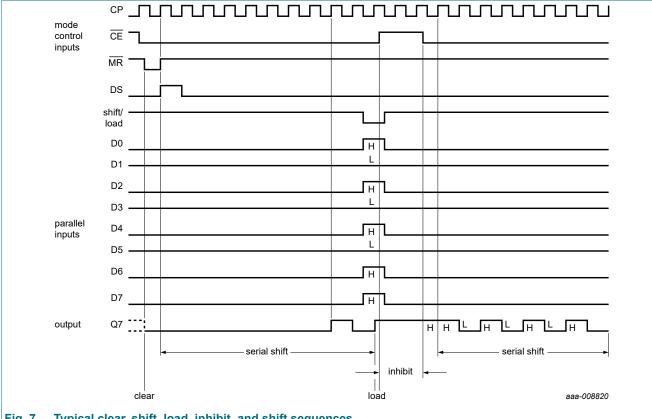
H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

q = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

 $X = don't care; \uparrow = LOW-to-HIGH clock transition.$

Operating modes	Inputs			Qn regi	Qn registers			
	PE	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7
parallel load	I	I	1	Х	I	L	L to L	L
	I	I	1	Х	h	Н	H to H	Н
serial shift	h	I	1	I	X	L	q0 to q5	q6
	h	I	1	h	X	Н	q0 to q5	q6
hold "do nothing"	Х	Н	Х	Х	Х	q0	q1 to q6	q7



Typical clear, shift, load, inhibit, and shift sequences Fig. 7.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CC}	supply voltage			-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
I _{OK}	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
lo	output current	-0.5 V < V _O < V _{CC} + 0.5 V		-	±25	mA
I _{CC}	supply current			-	50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C.

For SOT403-1 (TSSOP16) package: Ptot derates linearly with 8.5 mW/K above 91 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC166	5	74HCT166			Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC16	6	·								
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V

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Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	1
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±0.1	-	±1	-	±1	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	-	80	-	160	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT1	66			1	1					
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 5.2 mA; V _{CC} = 4.5 V	-	0.16	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 4.5 V$	-	-	±0.1	-	±1	-	±1	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 4.5$ V	-	-	8.0	-	80	-	160	μA
ΔI _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 V$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 V$ to 5.5 V								
		Dn and DS inputs	-	35	126	-	157.5	-	171.5	μA
		CP and CE inputs	-	80	288	-	360	-	392	μA
		MR input	-	40	144	-	180	-	196	μA
		PE input	-	60	216	-	270	-	294	μA
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND (ground = 0 V); $t_r = t_f = 6$ ns: $C_L = 50$ pF unless otherwise specified; for test circuit, see Fig. 11

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Мах	Min	Max	1
74HC16	6	1				I			1	
t _{pd}	propagation	CP to Q7; see Fig. 8 [1]							
	delay	V _{CC} = 2.0 V	-	50	150	-	190	-	225	ns
		V _{CC} = 4.5 V	-	18	30	-	38	-	45	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	15	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	14	26	-	33	-	38	ns
		MR to Q7; see Fig. 9								
		V _{CC} = 2.0 V	-	47	160	-	200	-	240	ns
		V _{CC} = 4.5 V	-	17	32	-	40	-	48	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	14	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	14	27	-	34	-	41	ns
t _t	transition	output; see Fig. 8	2]							
	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns
t _W	pulse width	CP input HIGH or LOW; see Fig. 8								
		V _{CC} = 2.0 V	80	17	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	6	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	5	-	17	-	20	-	ns
		MR input LOW; see Fig. 9								
		V _{CC} = 2.0 V	100	25	-	125	-	150	-	ns
		V _{CC} = 4.5 V	20	9	-	25	-	30	-	ns
		V _{CC} = 6.0 V	17	7	-	21	-	26	-	ns
t _{rec}	recovery	MR to CP; see Fig. 9								
	time	V _{CC} = 2.0 V	0	-19	-	0	-	0	-	ns
		V _{CC} = 4.5 V	0	-7	-	0	-	0	-	ns
		V _{CC} = 6.0 V	0	-6	-	0	-	0	-	ns
t _{su}	set-up time	Dn, CE to CP; see Fig. 10								
		V _{CC} = 2.0 V	80	14	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	5	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	4	-	17	-	20	-	ns
		PE to CP; see Fig. 10								
		V _{CC} = 2.0 V	100	33	-	125	-	150	-	ns
		V _{CC} = 4.5 V	20	12	-	25	-	30	-	ns
		V _{CC} = 6.0 V	17	10	-	21	-	26	-	ns

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Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Мах	1
t _h	hold time	Dn, CE to CP; see Fig. 10								
		V _{CC} = 2.0 V	2	-8	-	2	-	2	-	ns
		V _{CC} = 4.5 V	2	-3	-	2	-	2	-	ns
		V _{CC} = 6.0 V	2	-2	-	2	-	2	-	ns
		PE to CP; see Fig. 10								
		V _{CC} = 2.0 V	0	-28	-	0	-	0	-	ns
		V _{CC} = 4.5 V	0	-10	-	0	-	0	-	ns
		V _{CC} = 6.0 V	0	-8	-	0	-	0	-	ns
f _{max}	maximum	CP input; see Fig. 8								
	frequency	V _{CC} = 2.0 V	6	19	-	4.8	-	4	-	MHz
		V _{CC} = 4.5 V	30	57	-	24	-	20	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	63	-	-	-	-	-	MHz
		V _{CC} = 6.0 V	35	68	-	28	-	24	-	MHz
C _{PD}	power dissipation capacitance	per package; [: V _I = GND to V _{CC}	3] -	41	-	-	-	-	-	pF
74HCT1	66	1				1		1		
t _{pd}	propagation	CP to Q7; see Fig. 8	1]							
	delay	V _{CC} = 4.5 V	-	23	40	-	50	-	60	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	20	-	-	-	-	-	ns
		MR to Q7; see Fig. 9								
		V _{CC} = 4.5 V	-	22	40	-	50	-	60	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	19	-	-	-	-	-	ns
t _t	transition	output; see Fig. 8	2]							
	time	V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
t _W	pulse width	CP input HIGH or LOW; see <u>Fig. 8</u>								
		V _{CC} = 4.5 V	20	9	-	25	-	30	-	ns
		MR input LOW; see Fig. 9								
		V _{CC} = 4.5 V	25	11	-	31	-	38	-	ns
t _{rec}	recovery	MR to CP; see Fig. 9								
	time	V _{CC} = 4.5 V	0	-7	-	0	-	0	-	ns
t _{su}	set-up time	Dn, CE to CP; see Fig. 10								
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		PE to CP; see Fig. 10								
		V _{CC} = 4.5 V	30	15	-	38	-	45	-	ns
t _h	hold time	Dn, CE to CP; see Fig. 10								
		V _{CC} = 4.5 V	0	-3	-	0	-	0	-	ns
		PE to CP; see Fig. 10								
		V _{CC} = 4.5 V	0	-13	-	0	-	0	-	ns
f _{max}	maximum	CP input; see <u>Fig. 8</u>								
	frequency	V _{CC} = 4.5 V	25	45	-	20	-	17	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	50	-	-	-	-	-	MHz

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Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Тур	Мах	Min	Max	Min	Max]
C _{PD}	power dissipation capacitance	per package; [3] $V_I = GND$ to $V_{CC} - 1.5 V$	-	41	-	-	-	-	-	pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_t is the same as t_{THL} and t_{TLH} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

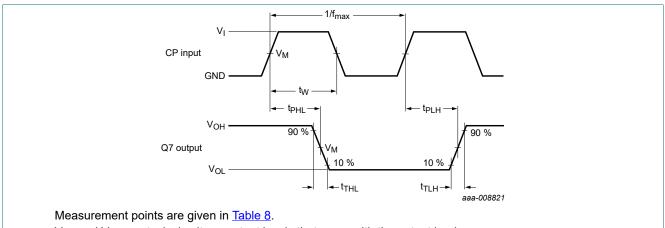
 $f_o = output$ frequency in MHz;

 Σ (C_L x V_{CC}² x f_o) = sum of outputs;

 C_L = output load capacitance in pF;

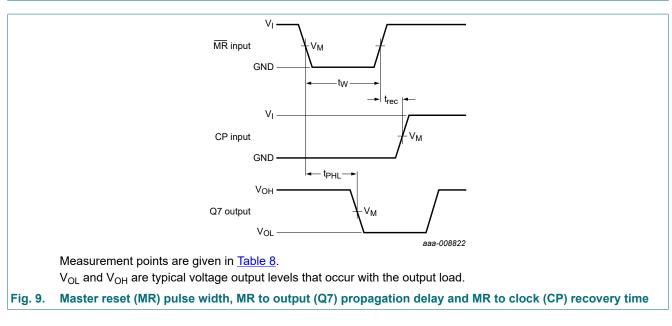
 V_{CC} = supply voltage in V.

10.1. Waveforms and test circuit



 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.





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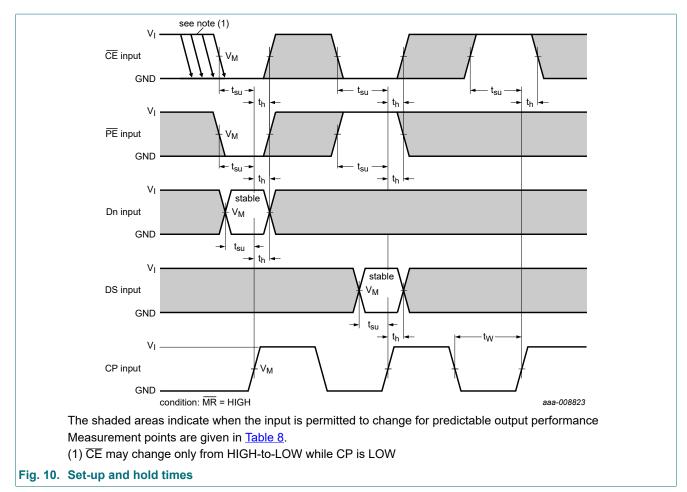


Table 8. Measurement points

Туре	Input		Output
	VI	V _M	V _M
74HC166	V _{CC}	0.5V _{CC}	0.5V _{CC}
74HCT166	3 V	1.3 V	1.3 V

8-bit parallel-in/serial out shift register

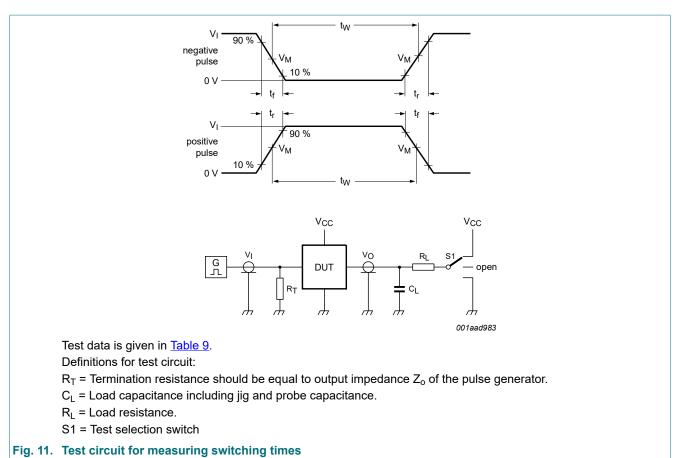


Table 9. Test data

Туре	Input		Load	S1 position	
	VI	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}
74HC166	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open
74HCT166	3 V	6 ns	15 pF, 50 pF	1 kΩ	open

11. Package outline

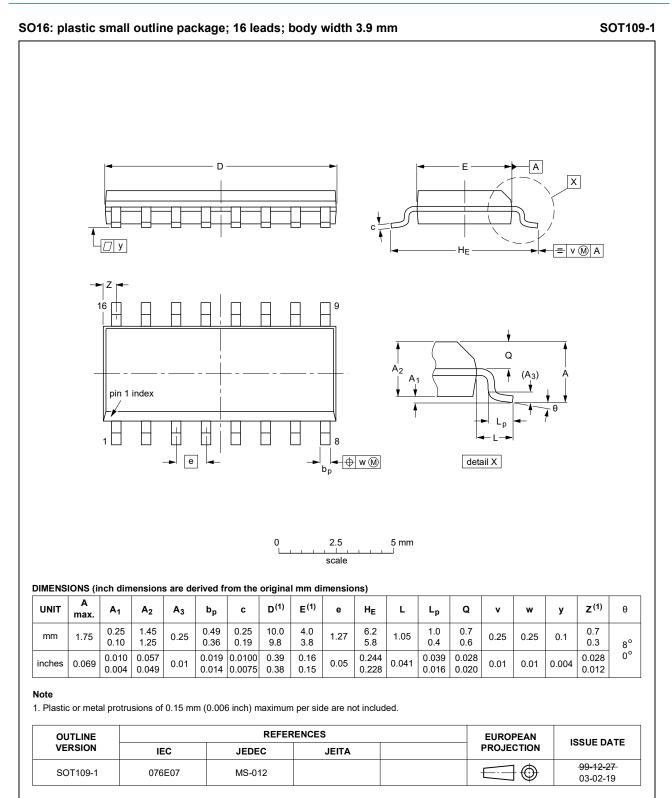


Fig. 12. Package outline SOT109-1 (SO16)

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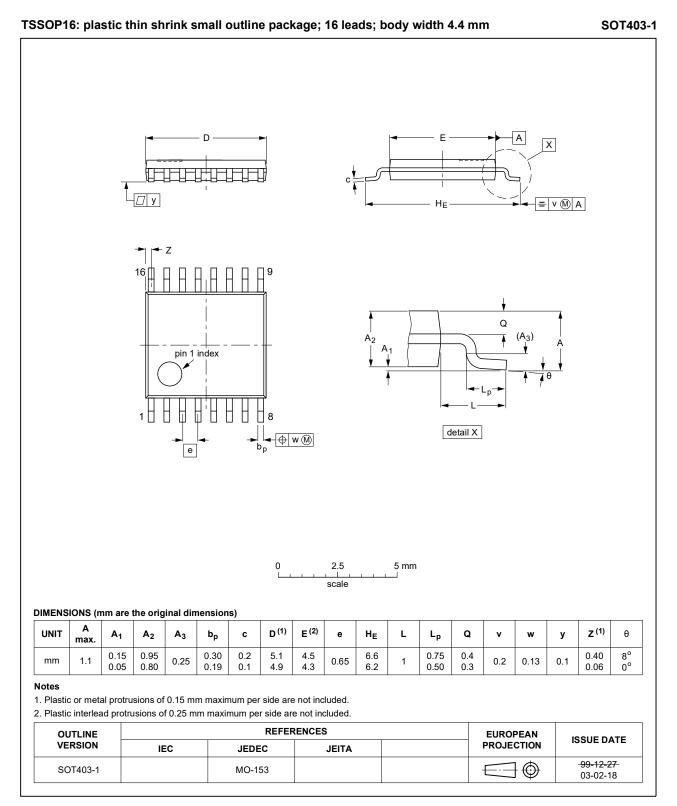


Fig. 13. Package outline SOT403-1 (TSSOP16)

⁷⁴HC_HCT166

12. Abbreviations

Table 10. Abbreviations				
Acronym	Description			
CMOS	Complementary Metal-Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
НВМ	Human Body Model			
ММ	Machine Model			
TTL	Transistor-Transistor Logic			

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC_HCT166 v.5	20210809	Product data sheet	-	74HC_HCT166 v.4	
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type number 74HCT166PW (SOT403-1/TSSOP16) added. Type numbers 74HC166DB and 74HCT166DB (SOT338-1/SSOP16) removed. <u>Section 2</u> updated. <u>Section 7</u>: Derating values for P_{tot} total power dissipation have been updated. 				
74HC_HCT166 v.4	20151228	Product data sheet	-	74HC_HCT166 v.3	
Modifications:	Type numbers	74HC166N and 74HCT166N	(SOT38-4) removed	l.	
74HC_HCT166 v.3	20130911	Product data sheet	-	74HC_HCT166_CNV v.2	
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. Family data added, see <u>Section 9</u> 				
74HC_HCT166_CNV v.2	December 1990	Product specification	-	-	

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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